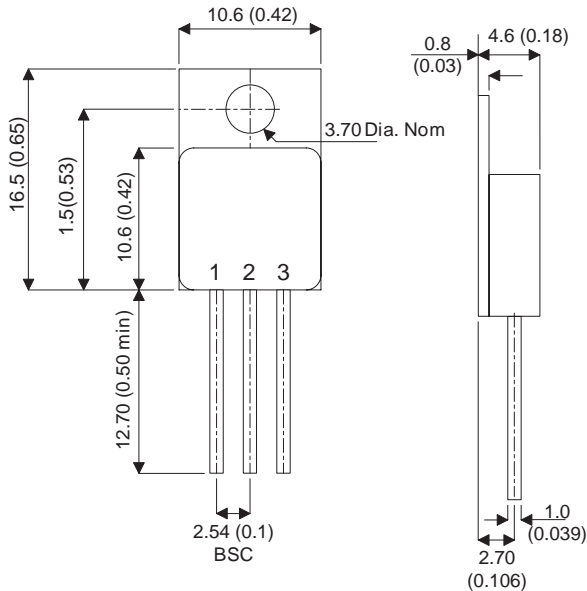


Dimensions in mm (inches).



N-Channel MOSFET in a Hermetically sealed TO257AB Metal Package.

$V_{DSS} = 200V$

$I_D = 9A$

$R_{DS(ON)} = 0.4\Omega$

All Semelab hermetically sealed products can be processed in accordance with the requirements of BS, CECC and JAN, JANTX, JANTXV and JANS specifications.

TO257AB (TO220M)

PINOUTS

1 – Gate 2 – Drain Case – Source

	Parameter	Min.	Typ.	Max.	Units
V_{DSS}	Drain – Source Breakdown Voltage			200	V
I_D	Continuous Drain Current			9	A
P_D	Power Dissipation			75	W
$R_{DS(ON)}$	Static Drain – Source On–State Resistance			0.4	Ω
C_{ISS}	Input Capacitance		600		pF
Q_g	Total Gate Charge			39	nC
$t_{td(on)}$	Turn–On Delay Time			35	ns
t_r	Rise Time			80	ns
$t_{td(off)}$	Turn–Off Delay Time			60	ns
t_f	Fall Time			40	ns

This is a shortform datasheet. For a full datasheet please contact sales@semelab.co.uk.

Semelab Plc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use.